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(54) **SEMICONDUCTOR DEVICE**

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(57)ABSTRACT

There is provided a semiconductor device 1 which comprises: a housing comprising a first housing electrode 5 and a second housing electrode 4 which are arranged at opposite sides of the housing; a plurality of semiconductor units 30 arranged within the housing between the first and second housing electrodes 4, 5; a plurality of pressure means 40 for applying pressure to the plurality of semiconductor units 30, respectively, wherein the plurality of pressure means 40 are arranged between the plurality of semiconductor units 30 and the first housing electrode 5; a first conductive structure 14 arranged between the plurality of pressure means 40 and the plurality of semiconductor units 30, wherein the plurality of semiconductor units 30 are electrically connected in parallel between the second housing electrode 4 and the first conductive structure 14; and a second conductive structure 18 configured to provide a current flow path from the first conductive structure 14 to the first housing electrode 5, the second conductive structure comprising a first part 16 that is fixedly connected to the first conductive structure 14 and a second part 9 that is fixedly connected to the first housing electrode 5.

